



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SC6094 — NPN Epitaxial Planar Silicon Transistor

High-Current Switching Applications

Applications

- DC / DC converter, relay drivers, lamp drivers, motor drivers, inverter

Features

- Adoption of FBET, MBIT process
- Low collector-to-emitter saturation voltage
- High allowable power dissipation
- Large current capacity
- High-speed switching

Specifications

Absolute Maximum Ratings at Ta=25°C

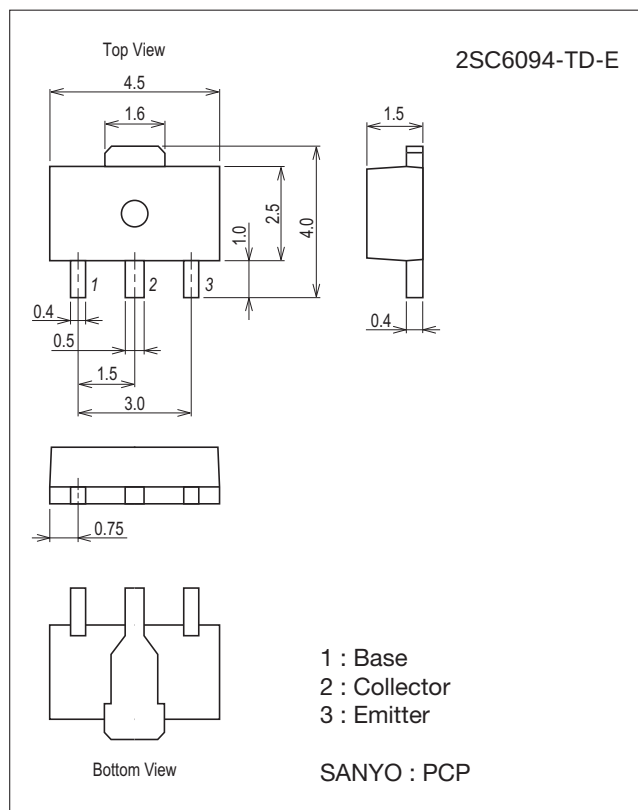
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		100	V
Collector-to-Emitter Voltage	VCES		100	V
	VCEO		60	V
Emitter-to-Base Voltage	VEBO		6.5	V
Collector Current	IC		3	A
Collector Current (Pulse)	ICP		5	A

Continued on next page.

Package Dimensions

unit : mm (typ)

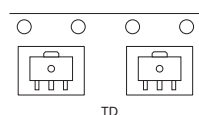
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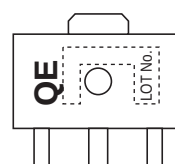
Product & Package Information

- Package : PCP
- JEITA, JEDEC : SC-62, SOT-89, TO-243
- Minimum Packing Quantity : 1,000 pcs./reel

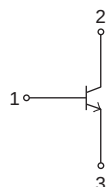
Packing Type: TD



Marking



Electrical Connection



SANYO Semiconductor Co., Ltd.

<http://www.sanyosemi.com/en/network/>

2SC6094

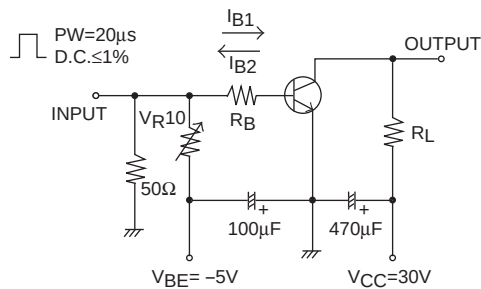
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Parameter	Symbol	Conditions	Ratings	Unit
Base Current	I_B		600	mA
Collector Dissipation	P_C	When mounted on ceramic substrate (250mm ² ×0.8mm)	1.3	W
		$T_c=25^{\circ}\text{C}$	3.5	W
Junction Temperature	T_j		150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^{\circ}\text{C}$

Electrical Characteristics at $T_a=25^{\circ}\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=50\text{V}, I_E=0\text{A}$			1	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4\text{V}, I_C=0\text{A}$			1	μA
DC Current Gain	h_{FE}	$V_{CE}=2\text{V}, I_C=100\text{mA}$	300		600	
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=500\text{mA}$		390		MHz
Output Capacitance	C_{ob}	$V_{CB}=10\text{V}, f=1\text{MHz}$		18		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C=1\text{A}, I_B=50\text{mA}$		90	135	mV
	$V_{CE(sat)2}$	$I_C=1\text{A}, I_B=100\text{mA}$		80	120	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1\text{A}, I_B=100\text{mA}$		0.84	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu\text{A}, I_E=0\text{A}$	100			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C=100\mu\text{A}, R_{BE}=0\Omega$	100			V
	$V_{(BR)CEO}$	$I_C=1\text{mA}, R_{BE}=\infty$	60			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu\text{A}, I_C=0\text{A}$	6.5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		35		ns
Storage Time	t_{stg}			680		ns
Fall Time	t_f			24		ns

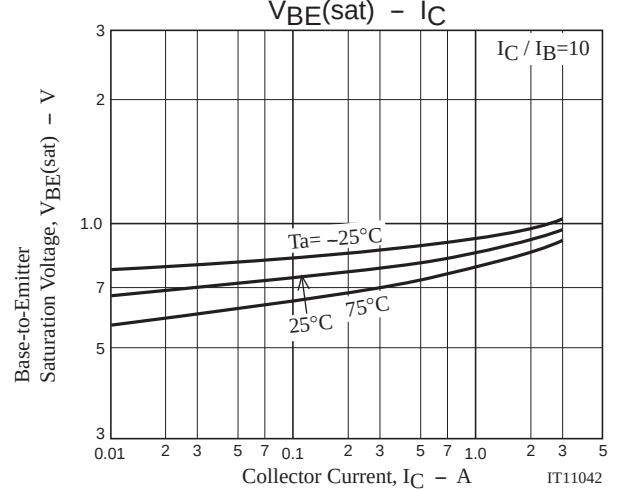
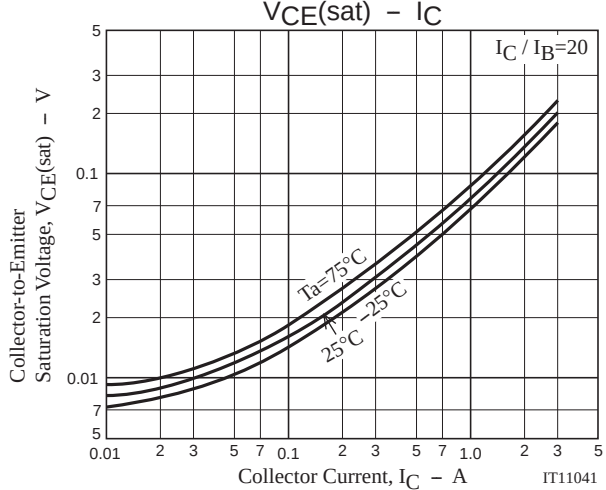
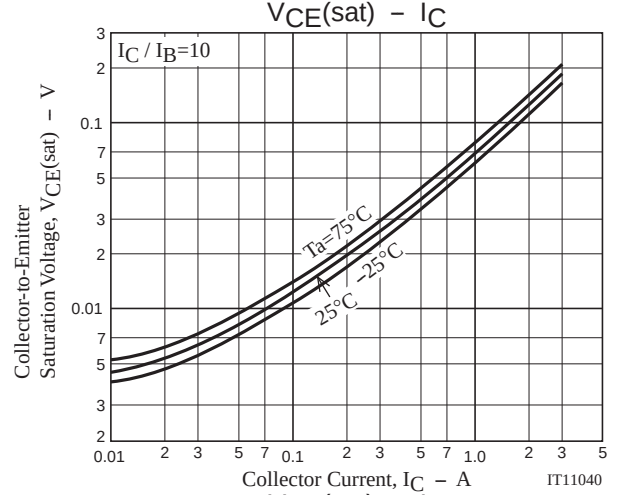
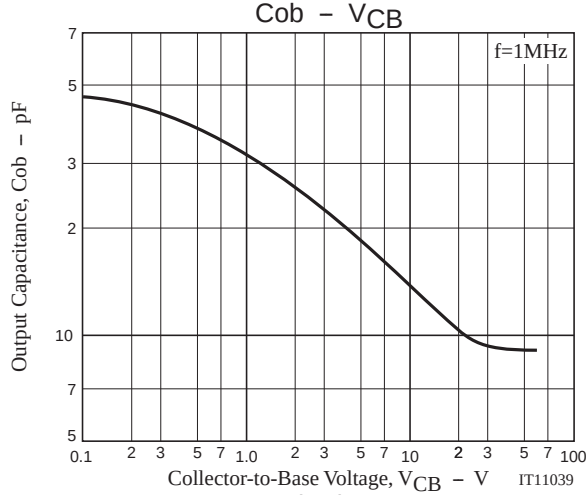
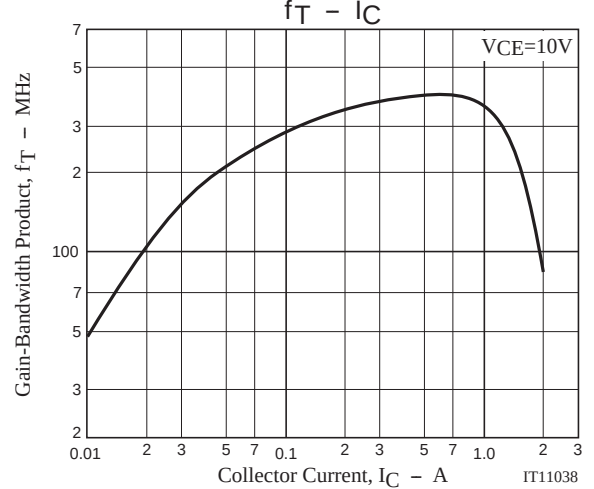
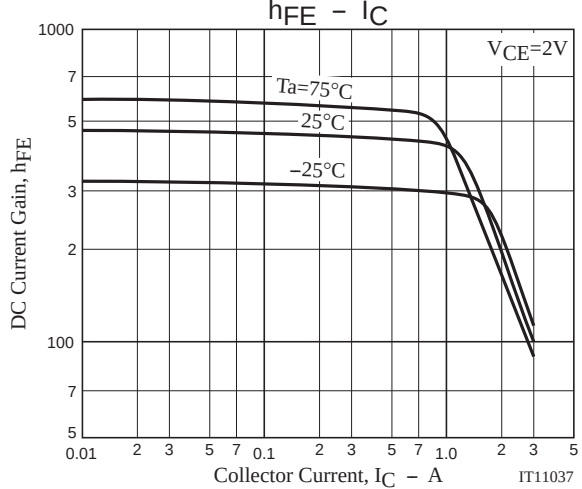
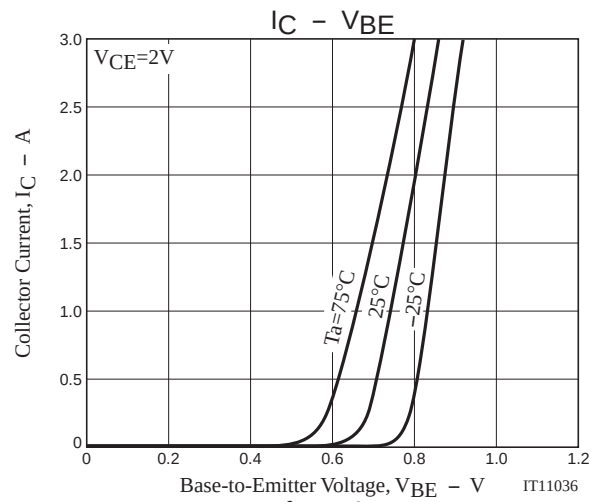
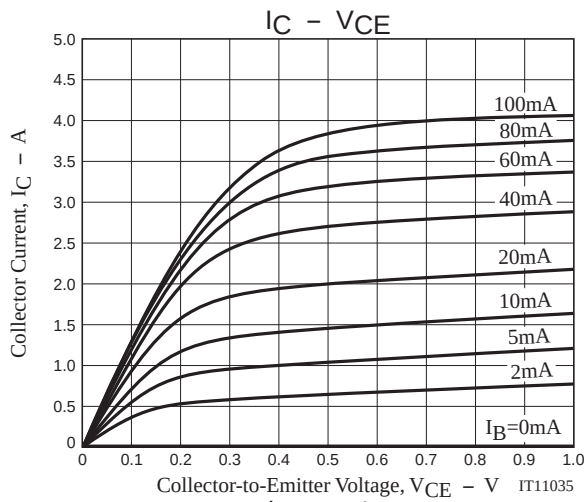
Switching Time Test Circuit

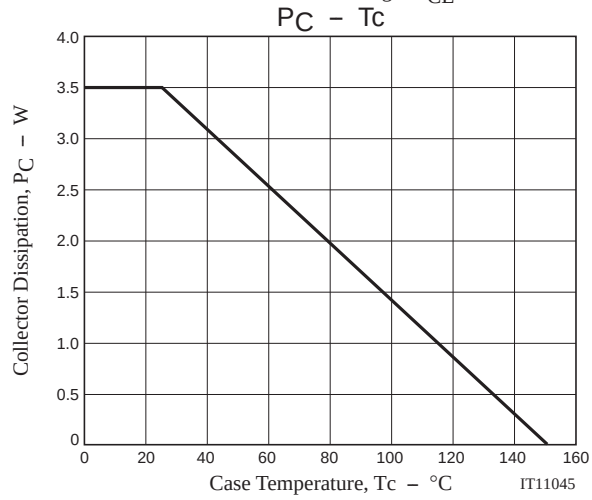
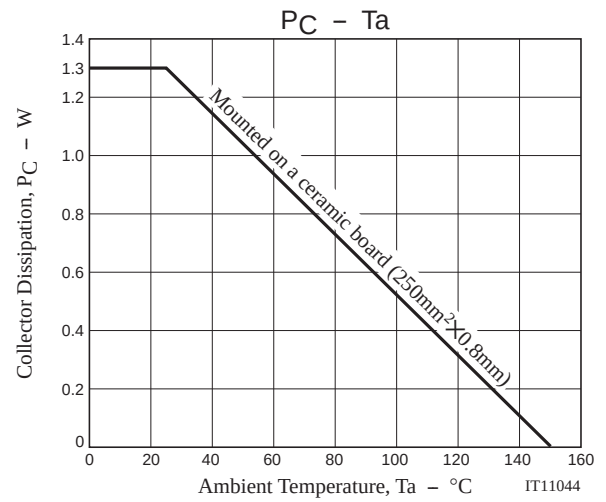
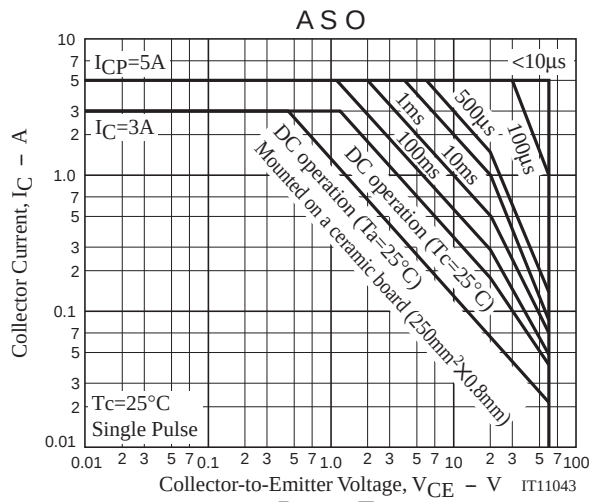


$$I_C=10I_{B1}=-10I_{B2}=0.5\text{A}$$

Ordering Information

Device	Package	Shipping	memo
2SC6094-TD-E	PCP	1,000pcs./reel	Pb Free



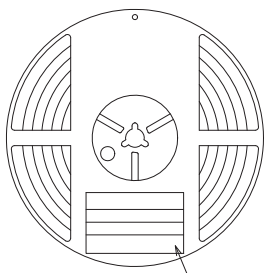


Embossed Taping Specification

2SC6094-TD-E

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
PCP	PCP	1,000	4,000	24,000	4 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method

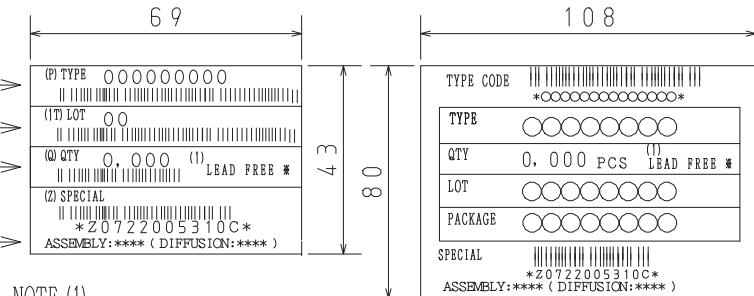
Reel label

Type No. →
 LOT No. →
 Quantity →
 Origin →

Reel label, Inner box label
 (unit:mm)

Outer box label

It is a label at the time of factory shipments.
 The form of a label may change in physical
 distribution process.



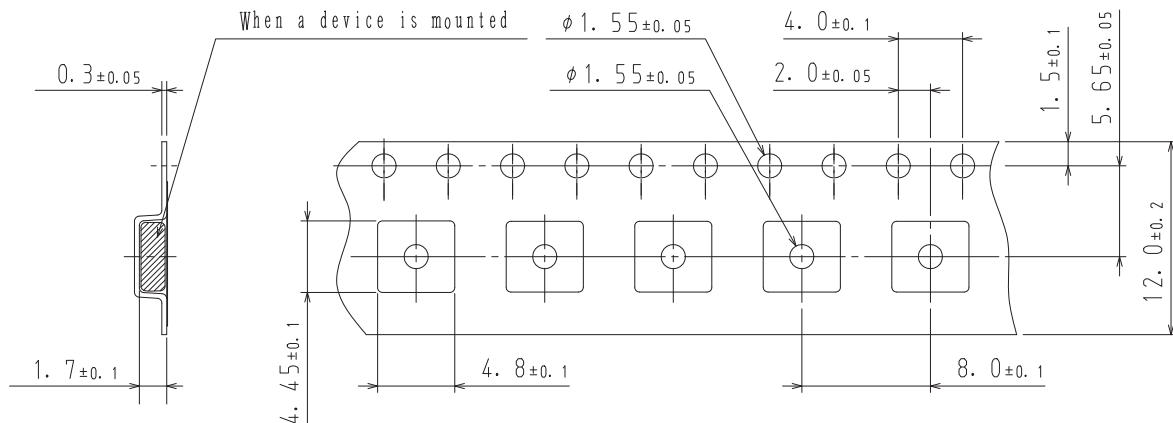
NOTE (1)

The LEAD FREE # description shows that the surface
 treatment of the terminal is lead free.

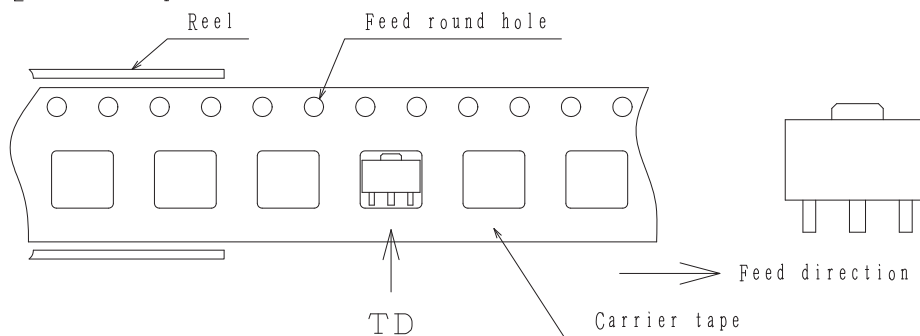
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

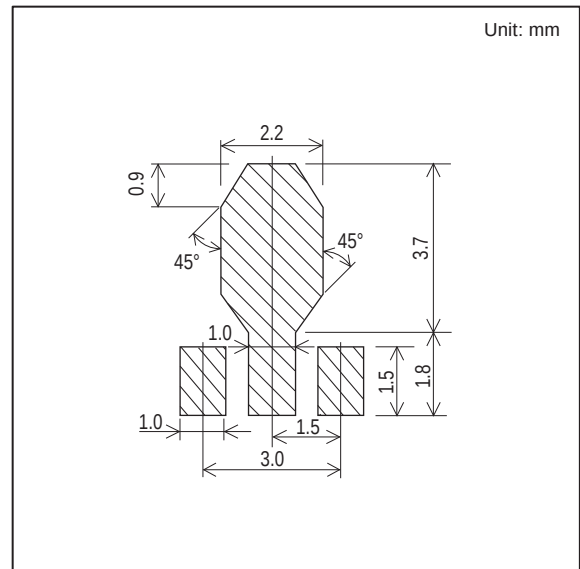
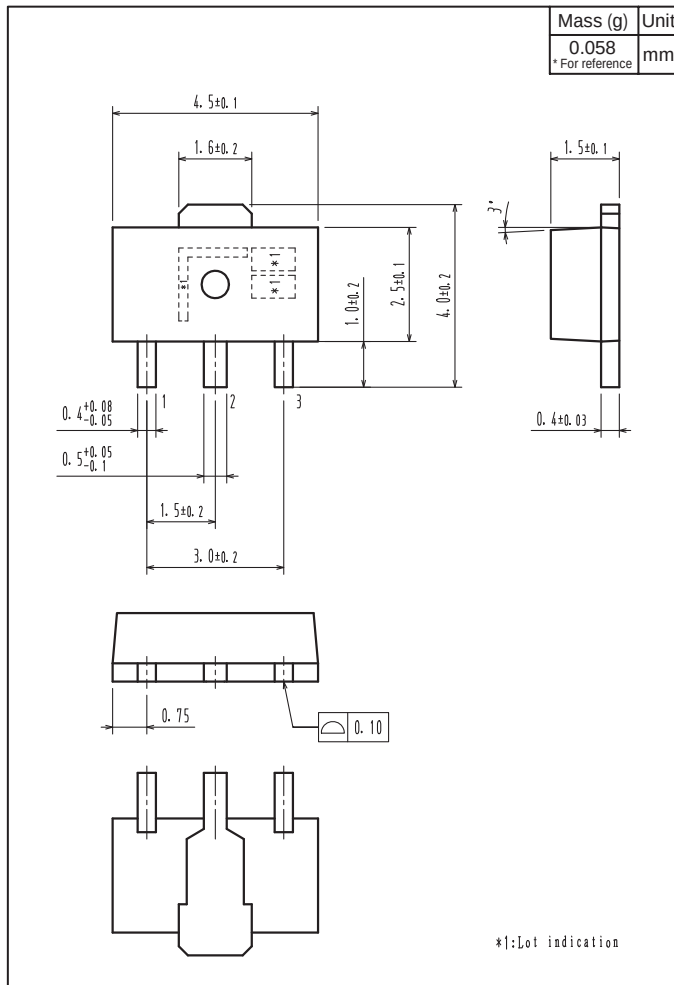


Those with pin 1 index on the feed hole side.....TD

Outline Drawing

2SC6094-TD-E

Land Pattern Example



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